



74HC594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74HC594 is a high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low, the shift regisister reset function (\overline{SHR}) sets all shift register values to zero and is independent of all clocks. Also when asserted low, the storage register reset function (\overline{STR}) sets all shift register values to zero and is independent of all clocks.

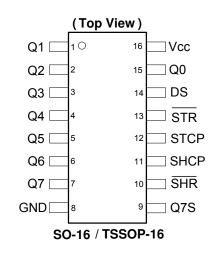
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or sources 8mA at V_{CC}= 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 6.0V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.
- Wide array of products such as:
 - Computer Peripherals
 - Appliances
 - Industrial Control
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

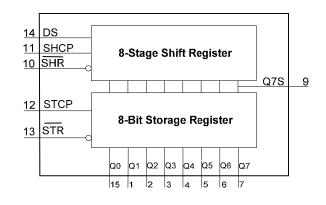
Click here for ordering information, located at the end of datasheet



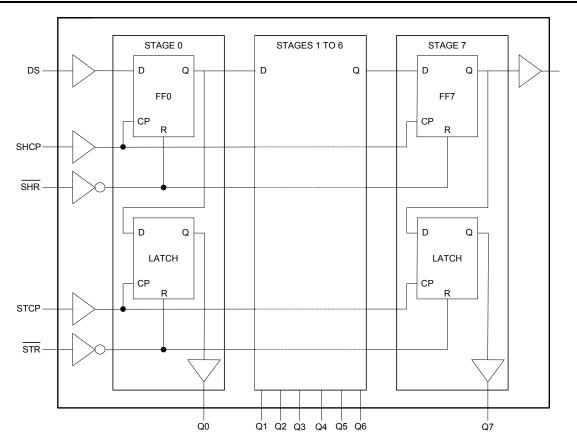
Pin Descriptions

n.	-	
Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram





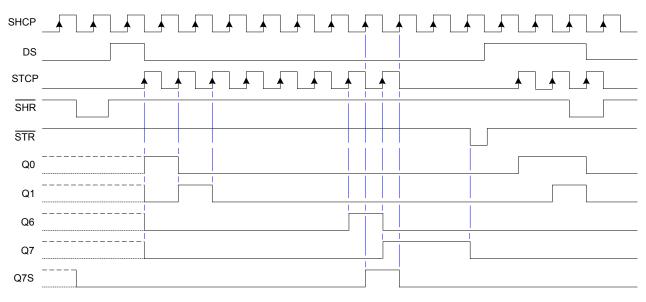
Functional Description and Timing Diagram

	Control			Input	Input Output		Function
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Х	Х	L NC		Clear Shift Register
Х	L	Х	Х	Х	NC L		Clear Storage Register
Н	Х	1	L	H or L	Q6S	Q6S NC Loads DS into shift register stage 0. All Q _S shifted	
Н	Н	Х	1	Х	NC Qs		Contents of shift register moved to starge register all $Q_S \rightarrow Q_N$
Н	Н	1	1	H or L	Q6S QnS		Shift Register one pulse count ahead of storage register.

H=HIGH voltage state L=LOW voltage state ^=LOW to HIGH transition

X= don't care - high or low (not floating)

NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	D	Rating	Unit	
ESD HBM	Human Body Model ESD Protect	ction	2	KV
ESD CDM	Charged Device Model ESD Pro	otection	1	KV
ESD MM	Machine Model ESD Protection		200	V
V _{CC}	Supply Voltage Range		-0.5 to +7.0	V
VI	Input Voltage Range		-0.5 to +7.0	V
Vo	Voltage applied to output in hig	h or low state	-0.3 to V _{CC} +0.5	V
lıк	Input Clamp Current VI < -0.5	-20	mA	
I _{IK}	Input Clamp Current VI > Vc	20	mA	
I _{ОК}	Output Clamp Current V _O <-0.	-20	mA	
Іок	Output Clamp Current V _O > V _O	_{CC} + 0.5V	20	mA
	Continuous output ourront	Q7 standard output	±25	mA
IO	Continuous output current	Qn bus driver outputs	±35	mA
Icc	Continuous current through Vcc		70	mA
I _{GND}	Continuous current through GN	-70	mA	
TJ	Operating Junction Temperature	-40 to +150	°C	
T _{STG}	Storage Temperature		-65 to +150	°C
P _{TOT}	Total Power Dissipation		500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	-	2.0	6.0	V
VI	Input Voltage	-	0	Vcc	V
Vo	Output Voltage	-	0	Vcc	V
		V _{CC} = 2.0V	-	1000	
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 4.5V$	-	500	ns/V
		V _{CC} = 6.0V	-	400	-
TA	Operating free-air temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	N	т	a = +25°	С	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Faranieter	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
		-	2.0V	1.5	1.2	-	1.5	-	1.5	-	
VIH	High-level Input Voltage	-	4.5V	3.15	2.4	-	3.15	-	3.15	-	V
	input voltage	-	6.0V	4.2	3.2	-	4.2	-	4.2	-	
		-	2.0V	-	0.8	0.5	-	0.5	-	0.5	
VIL	Low-level input voltage	-	4.5V	-	2.1	1.35	-	1.35	-	1.35	V
	input voltage	-	6.0V	-	2.8	1.8	-	1.8	-	1.8	
	High Level		2.0V	1.9	2.0	-	1.9	-	1.9	-	
	Output	I _{OH} = -20µA All outputs	4.5V	4.4	4.5	-	4.4	-	4.4	-	
	Voltage	All outputs	6.0V	5.9	6.0	-	5.9	-	5.9	-	
V _{OH}	070 autout	I _{OH} = -4mA	4.5V	3.98	4.32	-	3.84	-	3.7	-	V
	Q7S output	I _{OH} = -5.2mA	6.0V	5.48	5.81	-	5.34	-	5.2	-	
	Qn Bus	I _{OH} = -6.0mA	4.5V	3.98	4.32	_	3.84	_	3.7	-	
	Outputs	I _{OH} = -7.8mA	6.0V	5.48	5.81	-	5.34	-	5.2	-	
	Low-level		2.0V	-	0	0.1	-	0.1	-	0.1	
	Output	I _{OL} = 20μA All outputs	4.5V	-	0	0.1	-	0.1	-	0.1	
	Voltage	All outputs	6.0V	-	0	0.1	-	0.1	-	0.1	
V _{OL}	070 autout	I _{OL} = 4.0mA	4.5V	-	.15	0.26	-	0.33	-	0.4	V
	Q7S output	I _{OL} = 5.2mA	6.0V	-	.16	0.26	-	0.33	-	0.4	
	Qn Bus	I _{OL} = 6.0mA	4.5V	-	.15	0.26	-	0.33	-	0.4	
	Outputs	I _{OL} = 7.8mA	6.0V	-	.16	0.26	-	0.33	-	0.4	
lı	Input Current	V_{l} = GND to 5.5V	6.0V	-	-	±0.1	-	± 1	-	± 1	μA
Icc	Supply Current	$V_1 = GND \text{ or } V_{CC}$ $I_0 = 0$	6.0V	_	-	8.0	_	80	_	160	μΑ
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	6.0V	-	3.5	10	_	10	_	10	pF

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC} = 5V Typ	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF

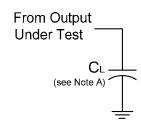


Switching Characteristics

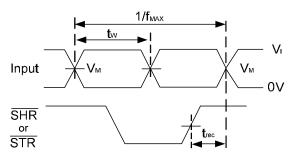
Symbol /				-	Γ _A = +25°	С	-40°C to	o +85°C	-40°C to	+125°C	Unit				
Parameter	Pins	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max					
			2.0V	6	30	_	4.8	_	4	_					
fMAX	SHCP or	Figure 2	4.5V	30	92	_	24	_	20	_					
Maximum Frequency	STCP	0	5.0V		100	_		_		_	MHz				
riequency			6.0V	35	109	_	28	_	24	_					
	SHCP		2.0V	80	10	_	100	_	120	_					
	HIGH or	Figure 2	4.5V	16	4	-	20	_	24	-					
	LOW		6.0V	14	3	-	17	_	20	-					
	STCP		2.0V	80	10	-	100	_	120	_					
t _W	HIGH or	Figure 2	4.5V	16	4	_	20	_	24	-	ns				
Pulse Width	LOW		6.0V	14	3	-	17	-	20	-					
	SHR and		2.0V	80	14	-	100	-	120	-					
	STR	Figure 2	4.5V	16	5	-	20	-	24	-					
	HIGH or LOW		6.0V	14	4	_	17	_	20	_					
	50.1		2.0V	100	10	-	125	-	150	-					
	DS to SHCP	Figure 2	4.5V	20	4	-	25	-	30	-	ns				
	01101		6.0V	17	3	-	21	-	26	-					
			2.0V	100	14	-	125	-	150	-					
t _{s∪} Set-up Time	SHR to STCP	Figure 2	4.5V	20	5	-	25	-	30	-	ns				
Set-up Time	0101		6.0V	17	4	-	21	-	26	-					
			2.0V	100	17	-	125	-	150	-					
	SHCP to STCP	Figure 2	4.5V	20	6	-	25	-	30	-	ns				
	0101	0.0.	0.01	0.01	0101		6.0V	17	5	-	21	-	26	-	
			2.0V	-	44	150	-	185	-	225					
	SHCP to	Figure 2	4.5V	_	16	30	-	37	-	45	ns				
	Q7S		5.0V	-	13	-	-	-	-	-	115				
t _{PD} Propagation			6.0V	-	14	26	-	31	-	38					
Delay			2.0V	-	44	150	-	185	-	225					
	STCP to	Figure 2	4.5V	-	16	30	-	37	-	45	ns				
	Qn		5.0V	_	13	-	-	_	-	_					
			6.0V	-	14	26	-	31	-	38					
t _H	DS to	Figure 2	2.0V	25	-8	-	30	_	35	_					
Hold Time	SHCP	r iguro 2	4.5V	5	-3	-	6	_	7	_	ns				
			6.0V	4	-2	-	5	_	6	_					
	SHR to	Figure 0	2.0V	50	-14	-	65	-	75	-					
t _{REC} Recovery Time	SHCP and STR to	Figure 2	4.5V	10	-5	-	13	-	15	-	ns				
Recovery mile	STCP		6.0V	9	-4	_	11	_	13	-					
			2.0V	-	39	150	-	185	-	225					
	SHR to	Figure 2	4.5V	-	14	30	-	37	-	45	ns				
t	Q7S	5	5.0V	-	11	-	-	-	-	-	-				
t _{PHL} Propagation			6.0V	-	12	26	-	31	-	38					
Delay			2.0V	_	39	125	-	155	-	185					
	STR to Qn	Figure 2	4.5V	-	14	25	-	31	-	37	ns				
	Since of		5.0V	_	11	-	-	-	-	-	-				
			6.0V	-	12	21	-	26	-	31					
	Serial data		2.0V	-	19	75	-	95	-	110					
	output Q7S	Figure 2	4.5V	-	7	15	-	19	-	22	ns				
t _{THL}			6.0V	-	6	13	-	16	-	19					
Transition Time	Parallel		2.0V	-	14	60	-	75	-	90					
	Data Outputs Ou	Figure 2	4.5V	-	5	12	-	15	-	18	ns				
Outputs Q _N		6.0V	-	4	10	-	13	-	15						



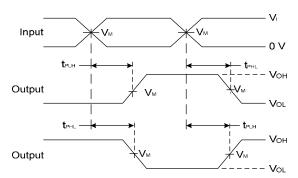
Parameter Measurement Information



V	Inj	outs	V	C	
V _{CC}	VI	t _r /t _f	V _M	CL	
2.0V	V _{CC}	6ns	V _{CC} /2	50pF	
4.5V	Vcc	6ns	V _{CC} /2	50pF	
5.0V	V _{CC}	6ns	V _{CC} /2	15pF	
6.0V	V _{CC}	6ns	V _{CC} /2	50pF	



Voltage Waveform Pulse Duration and Recovery Time



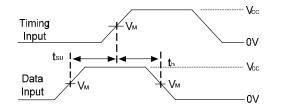
Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
- C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

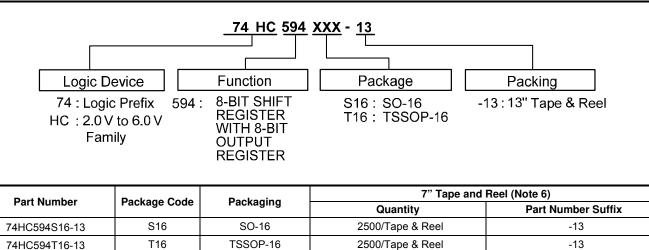
Figure 2 Load Circuit and Voltage Waveforms



Voltage Waveform Set-up and Hold Times

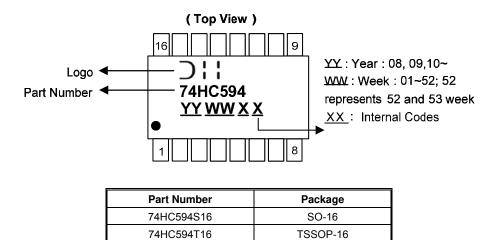


Ordering Information



Marking Information

(1) SO-16, TSSOP16

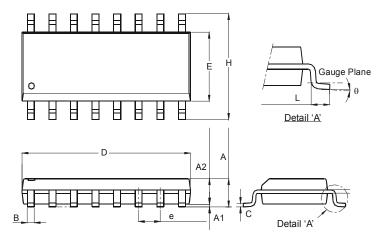




Package Outline Dimensions (All dimensions in mm.)

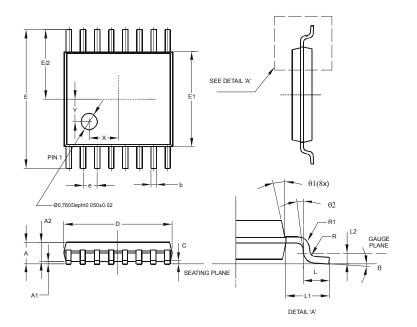
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



	SO-16						
Dim	Min	Max					
Α	1.40	1.75					
A1	0.10	0.25					
A2	1.30	1.50					
В	0.33	0.51					
С	0.19	0.25					
D	9.80	10.00					
Е	3.80	4.00					
е	1.27	Тур					
H	5.80	6.20					
L	0.38	1.27					
Θ	0 0° 8°						
All D	imension	s in mm					

Package Type: TSSOP-16



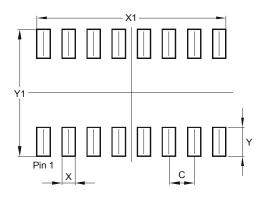
TSSOP-16						
Dim	Min	Min Max Typ				
Α	1	1.08	-			
A 1	0.05	0.15	-			
A2	0.80	0.93	-			
b	0.19	0.30	-			
С	0.09	0.20	-			
D	4.90	5.10	-			
Е	6	6.40 BS	SC			
E1	4.30 4.50 -					
е	0	.65 BS	SC			
L	0.45	0.75	-			
L1	1	.00 R	EF			
L2	0	.25 BS	SC			
R	0.09	1	-			
R1	0.09	1	-			
Х	1	1	1.350			
Y	1	1	1.050			
Θ	0°	8°	-			
Θ1	5°	15°	-			
Θ2	2 0°					
All D	Dimen	sions	in mm			



Suggested Pad Layout

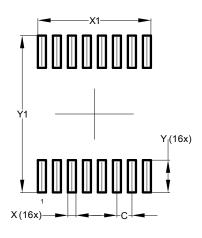
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Y	1.400
Y1	6.800



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